## NSN 5961-01-080-7921

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View Online at https://aerobasegroup.com/nsn/5961-01-080-7921 **Inclosure Material:** Metal **Overall Length:** Between 1.075 inches and 1.190 inches Overall Diameter: Between 0.428 inches and 0.435 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.428 inches and 0.435 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to emitter voltage/static/base open and 80.0 collector to base voltage, dc and 6.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 7.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 60.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator: Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

**Fiig:** A110a0

No